



100V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	Ι _D T _C = +25°C
100V -	30mΩ @ V _{GS} = 10V	28A
	45mΩ @ V _{GS} = 6.0V	23A

Description

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

Applications

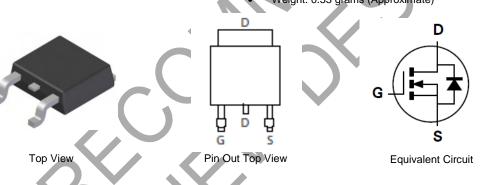
- Power Management Functions
- DC-DC Converters
- Backlighting

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low R_{DS(ON)} Minimizes Power Losses
- Low Q_G Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe Solderable per MIL-STD-202, Method 208 (3)
 - Weight: 0.33 grams (Approximate)



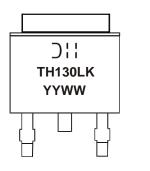
Ordering Information (Note 4)

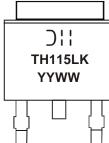
Part Number		Case	Packaging			
	DMTH10H030LK3-13	TO252 (DPAK)	2,500/Tape & Reel			
Notes:	: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.					
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"						
	and Lead-free.	ducto are defined as these which centers .000mm hree				

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





D'II = Manufacturer's Marking
TH130LK or TH115LK = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 17 = 2017)
WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	100	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current, V _{GS} = 10V	T _C = +25°C T _C = +100°C	I _D	28 18	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	150	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		I _{SM}	150	А
Maximum Continuous Body Diode Forward Current (Note 6)		ls	2.6	А
Avalanche Current, L = 3mH		I _{AS}	7.5	А
Avalanche Energy, L = 3mH		E _{AS}	85	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	2.1	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	69	°C/W
Total Power Dissipation (Note 6)		PD	3.5	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	42	°C/W
Thermal Resistance, Junction to Case		R _{eJC}	2	°C/VV
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +175	°C
		1.~		

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

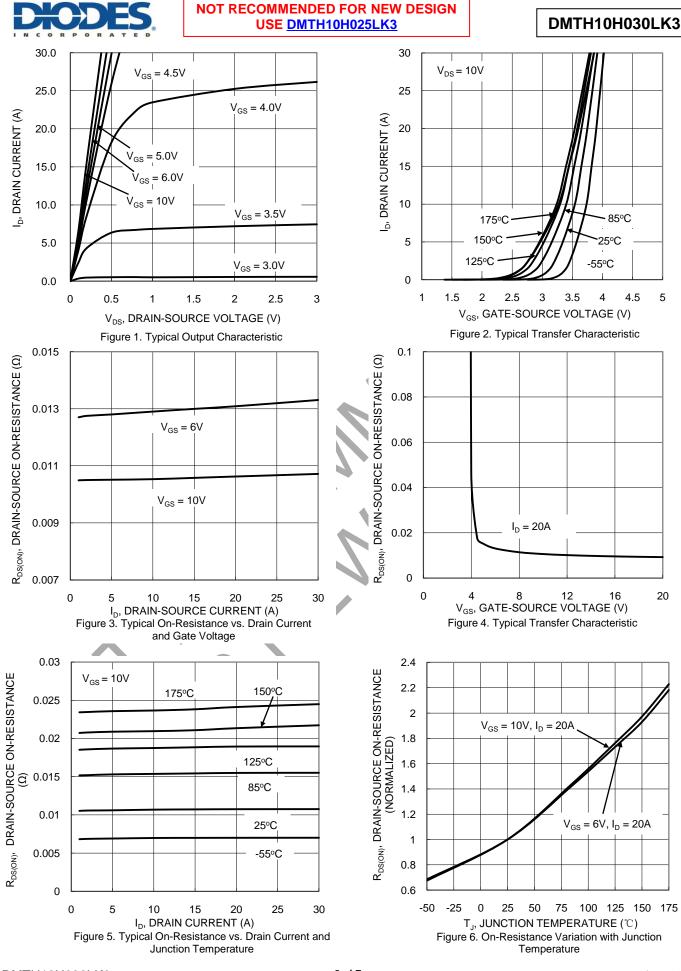
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	100	-		V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	-		1	μA	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}			±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)			*				
Gate Threshold Voltage	V _{GS(TH)}	1.4	-	3.5	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance				30	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Diani-Source On-Resistance	Rds(on)	-		45	11122	$V_{GS} = 6.0V, I_D = 20A$	
Diode Forward Voltage	V _{SD}			1.3	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	1,871	_			
Output Capacitance	C _{oss}	_	261	—	pF	$V_{DS} = 50V, V_{GS} = 0V$ f = 1MHz	
Reverse Transfer Capacitance	Crss	_	6.9	—			
Gate Resistance	R _G		0.75	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Q _G		33.3	—		$V_{DD} = 50V, I_D = 10A, V_{GS} = 10V$	
Gate-Source Charge	Q _{GS}		6.9	—	nC		
Gate-Drain Charge	Q _{GD}		5.1	—			
Turn-On Delay Time	t _{D(ON)}	-	6.5	—		$V_{DD} = 50V, V_{GS} = 10V,$ $I_D = 10A, R_G = 6\Omega$	
Turn-On Rise Time	t _R		7.0	—	ns		
Turn-Off Delay Time	t _{D(OFF)}		19.7	—	115		
Turn-Off Fall Time	t _F	—	8.1	—			
Reverse Recovery Time	t _{RR}	_	37.9	—	ns	L = 100 di/dt = 1000/up	
Reverse Recovery Charge	Q _{RR}	—	51.9	—	nC	I _F = 10A, di/dt = 100A/µs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

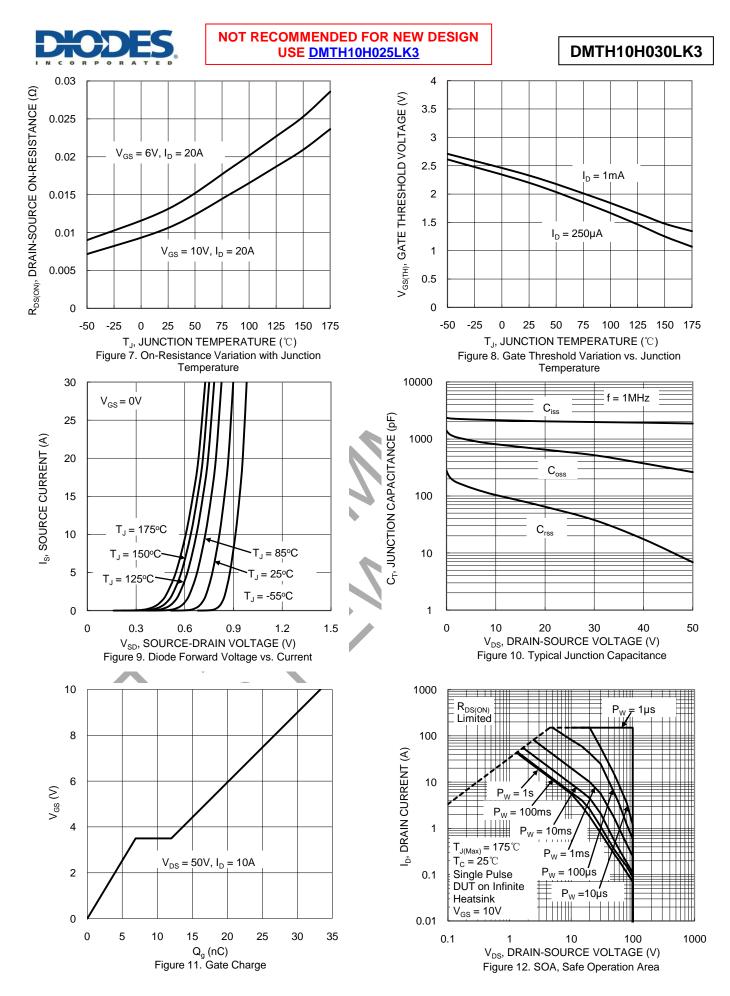
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



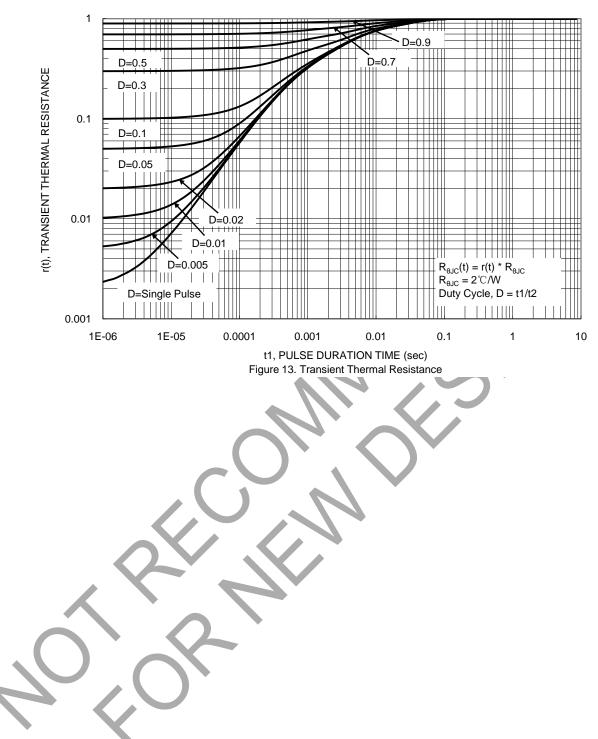
DMTH10H030LK3 Document number: DS38737 Rev. 3 - 3



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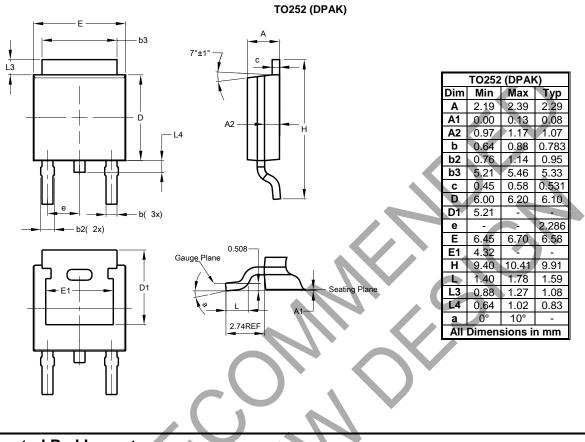
NOT RECOMMENDED FOR NEW DESIGN USE <u>DMTH10H025LK3</u>





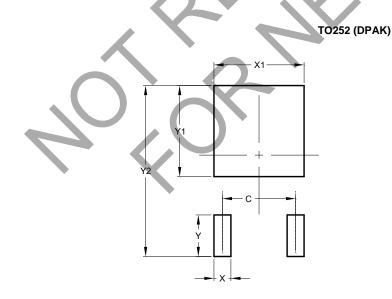
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700



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